

M393B1G73EB0-CMA

DRAM Module DDR3 SDRAM 8Gbyte 240RDIMM

Manufacturer: Samsung Semiconductor, Inc

Package/Case: BGA

Product Type: Memory

RoHS: RoHS Compliant/Lead free

Lifecycle: Obsolete



Images are for reference only

Inquiry

General Description

The M393B1G73EB0-CMA is a high-density DDR3L memory module designed for use in computer systems, servers, and other devices requiring higher memory capacities. DDR3L is an improved version of DDR3 memory, offering lower power consumption while maintaining compatibility with DDR3 standards.

Key Features Application

Memory Capacity: The "8GB" in the part number indicates that the memory module has a capacity of 8 gigabytes (GB). This makes it suitable for memory-intensive applications and multitasking scenarios.

Computer Systems

DDR3L Standard: The "L" in DDR3L stands for "Low Voltage," indicating that the memory module operates at a lower voltage compared to standard DDR3 memory. DDR3L operates at 1.35V or 1.5V, allowing for reduced power consumption and lower heat generation.

Servers

Memory Speed: The specific memory speed (clock frequency) of the module is usually specified in megahertz (MHz) or as a DDR rating (e.g., DDR3-1600, DDR3-1866). However, the exact speed of the M393B1G73EB0-CMA is not mentioned in the part number.

Workstations

ECC Support: Some memory modules come with Error Correction Code (ECC) support to detect and correct memory errors. However, this information is not included in the part number, so it is essential to refer to the product's datasheet or specifications for confirmation.

Data Centers

Form Factor: The memory module is typically designed to fit into a standard DIMM (Dual In-line Memory Module) slot in compatible systems.

Networking

Equipment

Recommended For You

M393A2G40EB1-CRC M393A2K40EB3-CWE

M393A1G43EB1-CRC

Samsung Semiconductor, Inc Samsung Semiconductor, Inc

Samsung Semiconductor, Inc

BGA - BGA

M393B2G70EB0-CMA

Samsung Semiconductor, Inc

BGA

K1S321611C-FI70

Samsung Semiconductor, Inc

BGA

K3P4V1000D-GC10

Samsung Semiconductor, Inc

DIP

K1S161611A-BI70

Samsung Semiconductor, Inc

BGA48

M393A2K43BB1-CRC

Samsung Semiconductor, Inc

BGA

K1S1616B1A-BI70

Samsung Semiconductor, Inc

TSOP50

K3P7V1000B-GC10

Samsung Semiconductor, Inc

BGA

K3P4V1000D-GC

Samsung Semiconductor, Inc

DIP

MB-MJ64GA/EU

Samsung Semiconductor, Inc

BGA

K3P4V1000D-TC10

Samsung Semiconductor, Inc

DIP

K3P4V1000D-TE10

Samsung Semiconductor, Inc

DIP

K3P4V1000D-TC

Samsung Semiconductor, Inc

DIP